MC7800, MC7800A, MC7800AE, NCV7800

1.0 A Positive Voltage Regulators

These voltage regulators are monolithic integrated circuits designed as fixed−voltage regulators for a wide variety of applications including local, on−card regulation. These regulators employ internal current limiting, thermal shutdown, and safe−area compensation. With adequate heatsinking they can deliver output currents in excess of 1.0 A. Although designed primarily as a fixed voltage regulator, these devices can be used with external components to obtain adjustable voltages and currents.

Features

- Output Current in Excess of 1.0 A
- No External Components Required
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe−Area Compensation
- Output Voltage Offered in 1.5%, 2% and 4% Tolerance
- Available in Surface Mount D^2PAK−3, DPAK−3 and Standard 3−Lead Transistor Packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These are Pb−Free Devices

MAXIMUM RATINGS (T_A = 25°C, unless otherwise noted)

Rating	Symbol	Value			Unit
		369C	221A	936	
Input Voltage (5.0 − 18 V) (24 V)	V_I	35 40			Vdc
Power Dissipation	P_D	Internally Limited			W
Thermal Resistance, Junction−to−Ambient	$R_{\theta JA}$	92	65	Figure 15	°C/W
Thermal Resistance, Junction−to−Case	$R_{\theta JC}$	5.0	5.0	5.0	°C/W
Storage Junction Temperature Range	T_{stg}	−65 to +150			°C
Operating Junction Temperature	T_J	+150			°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

*This device series contains ESD protection and exceeds the following tests:
Human Body Model 2000 V per MIL_STD_883, Method 3015.
Machine Model Method 200 V.

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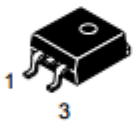
TO−220
T SUFFIX
CASE 221AB

Heatsink surface connected to Pin 2.



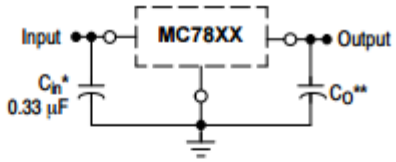
Pin 1. Input
2. Ground
3. Output

D^2PAK−3
D2T SUFFIX
CASE 936

Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.

DPAK−3
DT SUFFIX
CASE 369C

STANDARD APPLICATION



A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.

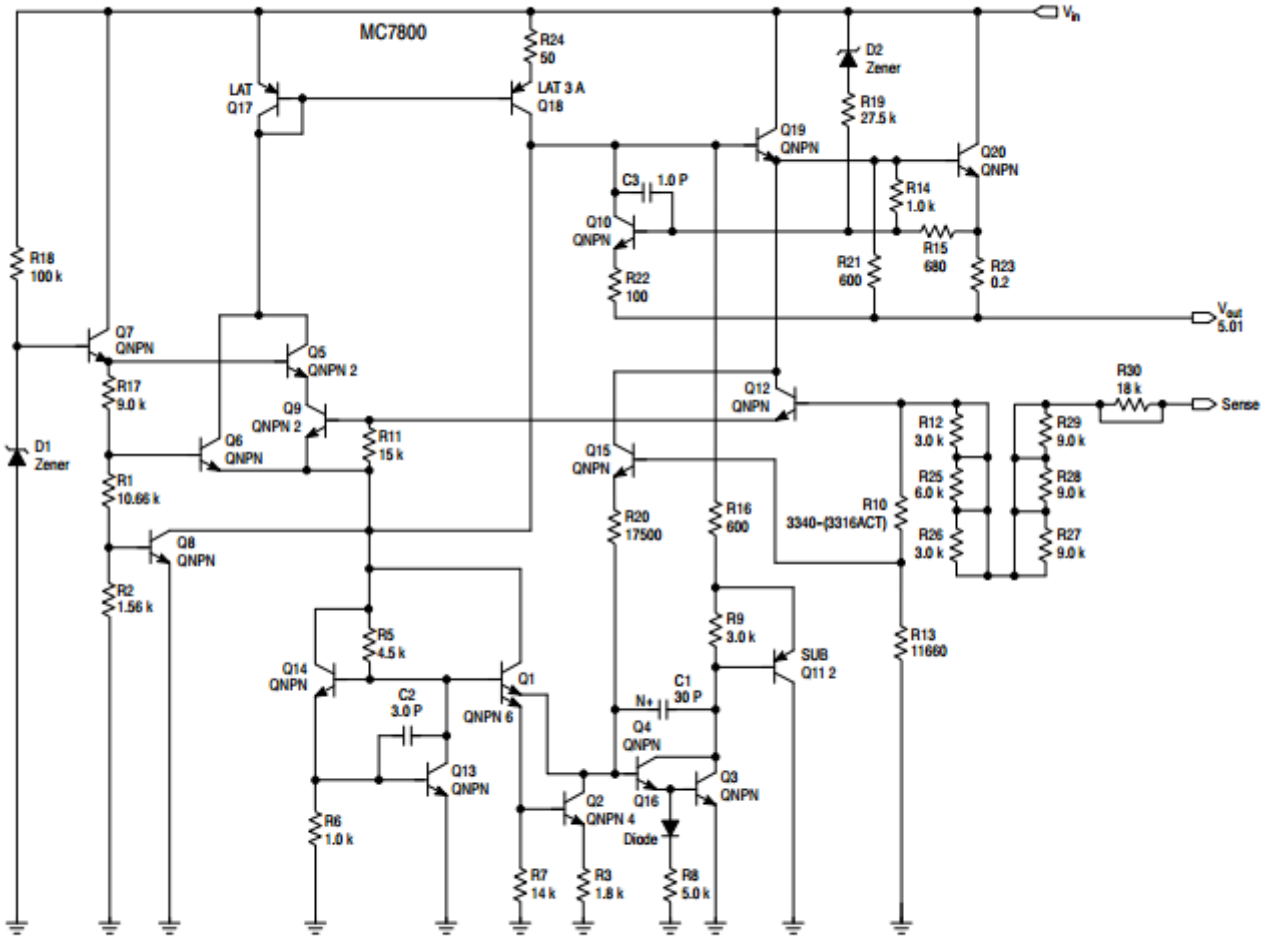
XX, These two digits of the type number indicate nominal voltage.

* C_{in} is required if regulator is located an appreciable distance from power supply filter.

** C_O is not needed for stability; however, it does improve transient response. Values of less than 0.1 μF could cause instability.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 23 of this data sheet.



This device contains 22 active transistors.

Figure 1. Representative Schematic Diagram

ELECTRICAL CHARACTERISTICS (V_{in} = 10 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 1), unless otherwise noted)

Characteristic	Symbol	MC7805B, NCV7805B			MC7805C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	4.8	5.0	5.2	4.8	5.0	5.2	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 7.0 Vdc ≤ V_{in} ≤ 20 Vdc 8.0 Vdc ≤ V_{in} ≤ 20 Vdc	V_O	 – 4.75	 – 5.0	 – 5.25	 4.75 –	 5.0 –	 5.25 –	Vdc
Line Regulation (Note 4) 7.5 Vdc ≤ V_{in} ≤ 20 Vdc, 1.0 A 8.0 Vdc ≤ V_{in} ≤ 12 Vdc	Reg_{line}	 – –	 5.0 1.3	 100 50	 – –	 0.5 0.8	 20 10	mV
Load Regulation (Note 4) 5.0 mA ≤ I_O ≤ 1.0 A 5.0 mA ≤ I_O ≤ 1.5 A (T_A = 25°C)	Reg_{load}	 – –	 1.3 0.15	 100 50	 – –	 1.3 1.3	 25 25	mV
Quiescent Current	I_B	–	3.2	8.0	–	3.2	6.5	mA
Quiescent Current Change 7.0 Vdc ≤ V_{in} ≤ 25 Vdc 5.0 mA ≤ I_O ≤ 1.0 A (T_A = 25°C)	ΔI_B	 – –	 – –	 – 0.5	 – –	 0.3 0.08	 1.0 0.8	mA
Ripple Rejection 8.0 Vdc ≤ V_{in} ≤ 18 Vdc, f = 120 Hz	RR	–	68	–	62	83	–	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	–	10	–	–	10	–	$\mu V/V_O$
Output Resistance f = 1.0 kHz	r_O	–	0.9	–	–	0.9	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	–	0.2	–	–	0.6	–	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.3	–	–	−0.3	–	mV/°C

1. T_{low} = 0°C for MC78XXC, MC78XXAC,
   = −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
2. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 10 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 3), unless otherwise noted)

Characteristic	Symbol	MC7805AB/MC7805AC/NCV7805AB			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	4.9	5.0	5.1	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 7.5 Vdc ≤ V_{in} ≤ 20 Vdc	V_O	 4.8	 5.0	 5.2	Vdc
Line Regulation (Note 4) 7.5 Vdc ≤ V_{in} ≤ 25 Vdc, I_O = 500 mA 8.0 Vdc ≤ V_{in} ≤ 12 Vdc, I_O = 1.0 A 8.0 Vdc ≤ V_{in} ≤ 12 Vdc, I_O = 1.0 A, T_J = 25°C 7.3 Vdc ≤ V_{in} ≤ 20 Vdc, I_O = 1.0 A, T_J = 25°C	Reg_{line}	 – – – –	 0.5 0.8 1.3 4.5	 10 12 4.0 10	mV
Load Regulation (Note 4) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A 250 mA ≤ I_O ≤ 750 mA	Reg_{load}	 – – –	 1.3 0.8 0.53	 25 25 15	mV
Quiescent Current	I_B	–	3.2	6.0	mA
Quiescent Current Change 8.0 Vdc ≤ V_{in} ≤ 25 Vdc, I_O = 500 mA 7.5 Vdc ≤ V_{in} ≤ 20 Vdc, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 0.3 – 0.08	 0.8 0.8 0.5	mA
Ripple Rejection 8.0 Vdc ≤ V_{in} ≤ 18 Vdc, f = 120 Hz, I_O = 500 mA	RR	68	83	–	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	$\mu V/V_O$
Output Resistance (f = 1.0 kHz)	r_O	–	0.9	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.3	–	mV/°C

3. T_{low} = 0°C for MC78XXC, MC78XXAC,
   = −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
4. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 11 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 5), unless otherwise noted)

Characteristic	Symbol	MC7806B/NCV7806B			MC7806C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	5.75	6.0	6.25	5.75	6.0	6.25	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 8.0 Vdc ≤ V_{in} ≤ 21 Vdc 9.0 Vdc ≤ V_{in} ≤ 21 Vdc	V_O	 – 5.7	 – 6.0	 – 6.3	 5.7 –	 6.0 –	 6.3 –	Vdc
Line Regulation, T_J = 25°C (Note 6) 8.0 Vdc ≤ V_{in} ≤ 25 Vdc 9.0 Vdc ≤ V_{in} ≤ 13 Vdc	Reg_{line}	 – –	 5.5 1.4	 120 60	 – –	 0.5 0.8	 24 12	mV
Load Regulation, T_J = 25°C (Note 6) 5.0 mA ≤ I_O ≤ 1.5 A	Reg_{load}	 –	 1.3	 120	 –	 1.3	 30	mV
Quiescent Current (T_J = 25°C)	I_B	–	3.3	8.0	–	3.3	8.0	mA
Quiescent Current Change 8.0 Vdc ≤ V_{in} ≤ 25 Vdc 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – –	 – –	 – 0.5	 – –	 0.3 0.08	 1.3 0.5	mA
Ripple Rejection 9.0 Vdc ≤ V_{in} ≤ 19 Vdc, f = 120 Hz	RR	 –	 65	 –	 58	 65	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	0.9	–	–	0.9	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.3	–	–	−0.3	–	mV/°C

5. T_{low} = 0°C for MC78XXC, MC78XXAC,
   = −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
6. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 11 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 7), unless otherwise noted)

Characteristic	Symbol	MC7806AC			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	5.88	6.0	6.12	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 8.6 Vdc ≤ V_{in} ≤ 21 Vdc	V_O	 5.76	 6.0	 6.24	Vdc
Line Regulation (Note 8) 8.6 Vdc ≤ V_{in} ≤ 25 Vdc, I_O = 500 mA 9.0 Vdc ≤ V_{in} ≤ 13 Vdc, I_O = 1.0 A	Reg_{line}	 – –	 5.0 1.4	 12 15	mV
Load Regulation (Note 8) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A 250 mA ≤ I_O ≤ 750 mA	Reg_{load}	 – – –	 1.3 0.9 0.2	 25 25 15	mV
Quiescent Current	I_B	–	3.3	6.0	mA
Quiescent Current Change 9.0 Vdc ≤ V_{in} ≤ 25 Vdc, I_O = 500 mA 9.0 Vdc ≤ V_{in} ≤ 21 Vdc, I_O = 1.0 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 – – –	 0.8 0.8 0.5	mA
Ripple Rejection 9.0 Vdc ≤ V_{in} ≤ 19 Vdc, f = 120 Hz, I_O = 500 mA	RR	 58	 65	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	μV/V_O
Output Resistance (f = 1.0 kHz)	r_O	–	0.9	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.3	–	mV/°C

7. T_{low} = 0°C for MC78XXC, MC78XXAC,
   = −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
8. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 14 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 9), unless otherwise noted)

Characteristic	Symbol	MC7808B/NCV7808B			MC7808C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	7.7	8.0	8.3	7.7	8.0	8.3	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 10.5 Vdc ≤ V_{in} ≤ 23 Vdc 11.5 Vdc ≤ V_{in} ≤ 23 Vdc	V_O	 – 7.6	 – 8.0	 – 8.4	 7.6 –	 8.0 –	 8.4 –	Vdc
Line Regulation, T_J = 25°C, (Note 10) 10.5 Vdc ≤ V_{in} ≤ 25 Vdc 11 Vdc ≤ V_{in} ≤ 17 Vdc	Reg_{line}	 – –	 6.0 1.7	 160 80	 – –	 6.0 1.7	 32 16	mV
Load Regulation, T_J = 25°C (Note 10) 5.0 mA ≤ I_O ≤ 1.5 A	Reg_{load}	 –	 1.4	 160	 –	 1.4	 35	mV
Quiescent Current	I_B	–	3.3	8.0	–	3.3	8.0	mA
Quiescent Current Change 10.5 Vdc ≤ V_{in} ≤ 25 Vdc 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – –	 – –	 – 0.5	 – –	 – –	 1.0 0.5	mA
Ripple Rejection 11.5 Vdc ≤ V_{in} ≤ 18 Vdc, f = 120 Hz	RR	 –	 62	 –	 56	 62	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	0.9	–	–	0.9	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.4	–	–	−0.4	–	mV/°C

9. T_{low} = 0°C for MC78XXC, MC78XXAC,
   = −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
10. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 14 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 11), unless otherwise noted)

Characteristic	Symbol	MC7808AB/MC7808AC/NCV7808AB			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	7.84	8.0	8.16	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 10.6 Vdc ≤ V_{in} ≤ 23 Vdc	V_O	 7.7	 8.0	 8.3	Vdc
Line Regulation (Note 12) 10.6 Vdc ≤ V_{in} ≤ 25 Vdc, I_O = 500 mA 11 Vdc ≤ V_{in} ≤ 17 Vdc, I_O = 1.0 A 10.4 Vdc ≤ V_{in} ≤ 23 Vdc, T_J = 25°C	Reg_{line}	 – – –	 6.0 1.7 5.0	 15 18 15	mV
Load Regulation (Note 12) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A 250 mA ≤ I_O ≤ 750 mA	Reg_{load}	 – – –	 1.4 1.0 0.22	 25 25 15	mV
Quiescent Current	I_B	–	3.3	6.0	mA
Quiescent Current Change 11 Vdc ≤ V_{in} ≤ 25 Vdc, I_O = 500 mA 10.6 Vdc ≤ V_{in} ≤ 23 Vdc, I_O = 1.0 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 – – –	 0.8 0.8 0.5	mA
Ripple Rejection 11.5 Vdc ≤ V_{in} ≤ 21.5 Vdc, f = 120 Hz, I_O = 500 mA	RR	 56	 62	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	0.9	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.4	–	mV/°C

11. T_{low} = 0°C for MC78XXC, MC78XXAC,
    = −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
12. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 15 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 13), unless otherwise noted)

Characteristic	Symbol	MC7809B/NCV7809B			MC7809C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	8.65	9.0	9.35	8.65	9.0	9.35	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 11.5 Vdc ≤ V_{in} ≤ 24 Vdc	V_O	8.55	9.0	9.45	8.55	9.0	9.45	Vdc
Line Regulation, T_J = 25°C (Note 14) 11 Vdc ≤ V_{in} ≤ 26 Vdc 11.5 Vdc ≤ V_{in} ≤ 17 Vdc	Reg_{line}	– –	6.2 1.8	32 16	– –	6.2 1.8	32 16	mV
Load Regulation, T_J = 25°C (Note 14) 5.0 mA ≤ I_O ≤ 1.5 A	Reg_{load}	–	1.5	35	–	1.5	35	mV
Quiescent Current	I_B	–	3.4	8.0	–	3.4	8.0	mA
Quiescent Current Change 11.5 Vdc ≤ V_{in} ≤ 26 Vdc 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	– –	– –	1.0 0.5	– –	– –	1.0 0.5	mA
Ripple Rejection 11.5 Vdc ≤ V_{in} ≤ 21.5 Vdc, f = 120 Hz	RR	56	61	–	56	61	–	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	–	10	–	–	10	–	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	1.0	–	–	1.0	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	–	0.2	–	–	0.2	–	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.5	–	–	−0.5	–	mV/°C

13. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
14. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 15 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 15), unless otherwise noted)

Characteristic	Symbol	MC7809AB/MC7809AC			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	8.82	9.0	9.18	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 11.5 Vdc ≤ V_{in} ≤ 24 Vdc	V_O	8.65	9.0	9.35	Vdc
Line Regulation (Note 16) 11.5 Vdc ≤ V_{in} ≤ 26 Vdc, I_O = 500 mA 12 Vdc ≤ V_{in} ≤ 17 Vdc, I_O = 1.0 A 11.5 Vdc ≤ V_{in} ≤ 24 Vdc, T_J = 25°C	Reg_{line}	– – –	6.2 1.8 5.2	16 7.0 16	mV
Load Regulation (Note 16) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A 250 mA ≤ I_O ≤ 750 mA	Reg_{load}	– – –	– – –	25 25 15	mV
Quiescent Current	I_B	–	3.3	6.0	mA
Quiescent Current Change 11.5 Vdc ≤ V_{in} ≤ 26 Vdc, I_O = 500 mA 11.5 Vdc ≤ V_{in} ≤ 24 Vdc, I_O = 1.0 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	– – –	– – –	0.8 0.8 0.5	mA
Ripple Rejection 11.5 Vdc ≤ V_{in} ≤ 21.5 Vdc, f = 120 Hz, I_O = 500 mA	RR	56	61	–	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	V_I _ V_O		2.0		Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	Vn	–	10	–	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	1.0	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	–	0.2	–	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.5	–	mV/°C

15. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB.
16. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 19 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 17), unless otherwise noted)

Characteristic	Symbol	MC7812B/NCV7812B			MC7812C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	11.5	12	12.5	11.5	12	12.5	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 14.5 Vdc ≤ V_{in} ≤ 27 Vdc 15.5 Vdc ≤ V_{in} ≤ 27 Vdc	V_O	 – 11.4	 – 12	 – 12.6	 11.4 –	 12 –	 12.6 –	Vdc
Line Regulation, T_J = 25°C (Note 18) 14.5 Vdc ≤ V_{in} ≤ 30 Vdc 16 Vdc ≤ V_{in} ≤ 22 Vdc 14.8 Vdc ≤ V_{in} ≤ 27 Vdc, I_O = 1.0 A	Reg_{line}	 – – –	 7.5 2.2 –	 240 120 –	 – – –	 3.8 0.3 –	 24 24 48	mV
Load Regulation, T_J = 25°C (Note 18) 5.0 mA ≤ I_O ≤ 1.5 A	Reg_{load}	 –	 1.6	 240	 –	 8.1	 60	mV
Quiescent Current	I_B	–	3.4	8.0	–	3.4	6.5	mA
Quiescent Current Change 14.5 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 1.0 A, T_J = 25°C 15 Vdc ≤ V_{in} ≤ 30 Vdc 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 – – –	 – 1.0 0.5	 – – –	 – – –	 0.7 0.8 0.5	mA
Ripple Rejection 15 Vdc ≤ V_{in} ≤ 25 Vdc, f = 120 Hz	RR	 –	 60	 –	 55	 60	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	1.1	–	–	1.1	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.8	–	–	−0.8	–	mV/°C

17. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
18. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 19 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 19), unless otherwise noted)

Characteristic	Symbol	MC7812AB/MC7812AC/NCV7812AB			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	11.75	12	12.25	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 14.8 Vdc ≤ V_{in} ≤ 27 Vdc	V_O	 11.5	 12	 12.5	Vdc
Line Regulation (Note 20) 14.8 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 500 mA 16 Vdc ≤ V_{in} ≤ 22 Vdc, I_O = 1.0 A 14.5 Vdc ≤ V_{in} ≤ 27 Vdc, T_J = 25°C	Reg_{line}	 – – –	 3.8 2.2 6.0	 18 20 120	mV
Load Regulation (Note 20) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	Reg_{load}	 – –	 – –	 25 25	mV
Quiescent Current	I_B	–	3.4	6.0	mA
Quiescent Current Change 15 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 500 mA 14.8 Vdc ≤ V_{in} ≤ 27 Vdc, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A, T_J = 25°C	ΔI_B	 – – –	 – – –	 0.8 0.8 0.5	mA
Ripple Rejection 15 Vdc ≤ V_{in} ≤ 25 Vdc, f = 120 Hz, I_O = 500 mA	RR	 55	 60	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	μV/V_O
Output Resistance (f = 1.0 kHz)	r_O	–	1.1	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−0.8	–	mV/°C

19. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
20. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 23 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 21), unless otherwise noted)

Characteristic	Symbol	MC7815B/NCV7815B			MC7815C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	14.4	15	15.6	14.4	15	15.6	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 17.5 Vdc ≤ V_{in} ≤ 30 Vdc 18.5 Vdc ≤ V_{in} ≤ 30 Vdc	V_O	 – 14.25	 – 15	 – 15.75	 14.25 –	 15 –	 15.75 –	Vdc
Line Regulation, T_J = 25°C (Note 22) 17.9 Vdc ≤ V_{in} ≤ 30 Vdc 20 Vdc ≤ V_{in} ≤ 26 Vdc	Reg_{line}	 – –	 8.5 3.0	 300 150	 – –	 8.5 3.0	 30 28	mV
Load Regulation, T_J = 25°C (Note 22) 5.0 mA ≤ I_O ≤ 1.5 A	Reg_{load}	 –	 1.8	 300	 –	 1.8	 55	mV
Quiescent Current	I_B	–	3.5	8.0	–	3.5	6.5	mA
Quiescent Current Change 17.5 Vdc ≤ V_{in} ≤ 30 Vdc 17.5 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 1.0 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 – – –	 – 1.0 0.5	 – – –	 – – –	 0.8 0.7 0.5	mA
Ripple Rejection 18.5 Vdc ≤ V_{in} ≤ 28.5 Vdc, f = 120 Hz	RR	 –	 58	 –	 54	 58	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	1.2	–	–	1.2	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−1.0	–	–	−1.0	–	mV/°C

21. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
22. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 23 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 23), unless otherwise noted)

Characteristic	Symbol	MC7815AB/MC7815AC			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	14.7	15	15.3	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 17.9 Vdc ≤ V_{in} ≤ 30 Vdc	V_O	 14.4	 15	 15.6	Vdc
Line Regulation (Note 24) 17.9 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 500 mA 20 Vdc ≤ V_{in} ≤ 26 Vdc 17.5 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 1.0 A, T_J = 25°C	Reg_{line}	 – – –	 8.5 3.0 7.0	 20 22 20	mV
Load Regulation (Note 24) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A 250 mA ≤ I_O ≤ 750 mA	Reg_{load}	 – – –	 1.8 1.5 1.2	 25 25 15	mV
Quiescent Current	I_B	–	3.5	6.0	mA
Quiescent Current Change 17.5 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 500 mA 17.5 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 1.0 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 – – –	 0.8 0.8 0.5	mA
Ripple Rejection 18.5 Vdc ≤ V_{in} ≤ 28.5 Vdc, f = 120 Hz, I_O = 500 mA	RR	 60	 80	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	1.2	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−1.0	–	mV/°C

23. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
24. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 27 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 25), unless otherwise noted)

Characteristic	Symbol	MC7818B			MC7818C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	17.3	18	18.7	17.3	18	18.7	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 21 Vdc ≤ V_{in} ≤ 33 Vdc 22 Vdc ≤ V_{in} ≤ 33 Vdc	V_O	 – 17.1	 – 18	 – 18.9	 17.1 –	 18 –	 18.9 –	Vdc
Line Regulation, (Note 26) 21 Vdc ≤ V_{in} ≤ 33 Vdc 24 Vdc ≤ V_{in} ≤ 30 Vdc	Reg_{line}	 – –	 9.5 3.2	 360 180	 – –	 9.5 3.2	 50 25	mV
Load Regulation, (Note 26) 5.0 mA ≤ I_O ≤ 1.5 A	Reg_{load}	 –	 2.0	 360	 –	 2.0	 55	mV
Quiescent Current	I_B	–	3.5	8.0	–	3.5	6.5	mA
Quiescent Current Change 21 Vdc ≤ V_{in} ≤ 33 Vdc 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – –	 – –	 – 0.5	 – –	 – –	 1.0 0.5	mA
Ripple Rejection 22 Vdc ≤ V_{in} ≤ 33 Vdc, f = 120 Hz	RR	 –	 57	 –	 53	 57	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_{II} - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	1.3	–	–	1.3	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−1.5	–	–	−1.5	–	mV/°C

25. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
26. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 27 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 27), unless otherwise noted)

Characteristic	Symbol	MC7818AC			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	17.64	18	18.36	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 21 Vdc ≤ V_{in} ≤ 33 Vdc	V_O	 17.3	 18	 18.7	Vdc
Line Regulation (Note 28) 21 Vdc ≤ V_{in} ≤ 33 Vdc, I_O = 500 mA 24 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 1.0 A 24 Vdc ≤ V_{in} ≤ 30 Vdc, I_O = 1.0 A, T_J = 25°C 20.6 Vdc ≤ V_{in} ≤ 33 Vdc, I_O = 1.0 A, T_J = 25°C	Reg_{line}	 – – – –	 9.5 3.2 3.2 8.0	 22 25 10.5 22	mV
Load Regulation (Note 28) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A 250 mA ≤ I_O ≤ 750 mA	Reg_{load}	 – – –	 2.0 1.8 1.5	 25 25 15	mV
Quiescent Current	I_B	–	3.5	6.0	mA
Quiescent Current Change 21 Vdc ≤ V_{in} ≤ 33 Vdc, I_O = 500 mA 21.5 Vdc ≤ V_{in} ≤ 30 Vdc, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 – – –	 0.8 0.8 0.5	mA
Ripple Rejection 22 Vdc ≤ V_{in} ≤ 32 Vdc, f = 120 Hz, I_O = 500 mA	RR	 53	 57	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	μV/V_O
Output Resistance f = 1.0 kHz	r_O	–	1.3	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−1.5	–	mV/°C

27. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
28. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 33 V, I_O = 500 mA, T_J = T_{low} to 125°C (Note 29), unless otherwise noted)

Characteristic	Symbol	MC7824B			MC7824C			Unit
		Min	Typ	Max	Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	23	24	25	23	24	25	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 27 Vdc ≤ V_{in} ≤ 38 Vdc 28 Vdc ≤ V_{in} ≤ 38 Vdc	V_O	 – 22.8	 – 24	 – 25.2	 22.8 –	 24 –	 25.2 –	Vdc
Line Regulation, (Note 30) 27 Vdc ≤ V_{in} ≤ 38 Vdc 30 Vdc ≤ V_{in} ≤ 36 Vdc	Reg_{line}	 – –	 11.5 3.8	 480 240	 – –	 2.7 2.7	 60 48	mV
Load Regulation, (Note 30) 5.0 mA ≤ I_O ≤ 1.5 A	Reg_{load}	 –	 2.1	 480	 –	 4.4	 65	mV
Quiescent Current	I_B	–	3.6	8.0	–	3.6	6.5	mA
Quiescent Current Change 27 Vdc ≤ V_{in} ≤ 38 Vdc 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – –	 – –	 – 0.5	 – –	 – –	 1.0 0.5	mA
Ripple Rejection 28 Vdc ≤ V_{in} ≤ 38 Vdc, f = 120 Hz	RR	 –	 54	 –	 50	 54	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	 –	 10	 –	$\mu V/V_O$
Output Resistance f = 1.0 kHz	r_O	–	1.4	–	–	1.4	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−2.0	–	–	−2.0	–	mV/°C

29. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
30. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

ELECTRICAL CHARACTERISTICS (V_{in} = 33 V, I_O = 1.0 A, T_J = T_{low} to 125°C (Note 31), unless otherwise noted)

Characteristic	Symbol	MC7824AC			Unit
		Min	Typ	Max	
Output Voltage (T_J = 25°C)	V_O	23.5	24	24.5	Vdc
Output Voltage (5.0 mA ≤ I_O ≤ 1.0 A, P_D ≤ 15 W) 27.3 Vdc ≤ V_{in} ≤ 38 Vdc	V_O	23.2	24	25.8	Vdc
Line Regulation (Note 32) 27 Vdc ≤ V_{in} ≤ 38 Vdc, I_O = 500 mA 30 Vdc ≤ V_{in} ≤ 36 Vdc, I_O = 1.0 A 30 Vdc ≤ V_{in} ≤ 36 Vdc, T_J = 25°C 26.7 Vdc ≤ V_{in} ≤ 38 Vdc, I_O = 1.0 A, T_J = 25°C	Reg_{line}	 – – – –	 11.5 3.8 3.8 10	 25 28 12 25	mV
Load Regulation (Note 32) 5.0 mA ≤ I_O ≤ 1.5 A, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A 250 mA ≤ I_O ≤ 750 mA	Reg_{load}	 – – –	 2.1 2.0 1.8	 15 25 15	mV
Quiescent Current	I_B	–	3.6	6.0	mA
Quiescent Current Change 27.3 Vdc ≤ V_{in} ≤ 38 Vdc, I_O = 500 mA 27 Vdc ≤ V_{in} ≤ 38 Vdc, T_J = 25°C 5.0 mA ≤ I_O ≤ 1.0 A	ΔI_B	 – – –	 – – –	 0.8 0.8 0.5	mA
Ripple Rejection 28 Vdc ≤ V_{in} ≤ 38 Vdc, f = 120 Hz, I_O = 500 mA	RR	 45	 54	 –	dB
Dropout Voltage (I_O = 1.0 A, T_J = 25°C)	$V_I - V_O$	–	2.0	–	Vdc
Output Noise Voltage (T_A = 25°C) 10 Hz ≤ f ≤ 100 kHz	V_n	 –	 10	 –	μV/V_O
Output Resistance (f = 1.0 kHz)	r_O	–	1.4	–	mΩ
Short Circuit Current Limit (T_A = 25°C) V_{in} = 35 Vdc	I_{SC}	 –	 0.2	 –	A
Peak Output Current (T_J = 25°C)	I_{max}	–	2.2	–	A
Average Temperature Coefficient of Output Voltage	TCV_O	–	−2.0	–	mV/°C

31. T_{low} = 0°C for MC78XXC, MC78XXAC,
= −40°C for NCV78XX, MC78XXB, MC78XXAB, and MC78XXAEB
32. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.